

IGBT Modules

V_{CES}	1200V
I_C	450A



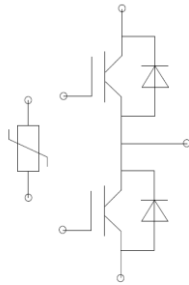
Applications

- Motion/sevo control
- High frequency switching application
- UPS (Uninterruptible Power Supplies)
- Welding machine

Features

- Low $V_{CE(sat)}$ with trench technology
- Low switching losses especially E_{off}
- $V_{ce(sat)}$ with positive temperature coefficient
- High short circuit capability(10us)
- Including ultra fast & soft recovery anti-parallel FWD
- Low inductance package
- Maximum junction temperature 175°C

Circuit



● IGBT

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Collector-Emitter Voltage	V_{CES}	$V_{GE}=0V, I_C=1mA, T_{vj}=25^{\circ}C$	1200	V
Continuous Collector Current	I_C	$T_c=100^{\circ}C$	450	A
Repetitive Peak Collector Current	I_{CRM}	$t_p=1ms$	900	A
Gate-Emitter Voltage	V_{GES}	$T_{vj}=25^{\circ}C$	± 20	V
Total Power Dissipation	P_{tot}	$T_c=25^{\circ}C$ $T_{vjmax}=175^{\circ}C$	2340	W



Characteristic Values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Gate-emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=12mA, T_{vj}=25^{\circ}C$	5.2	5.8	6.4	V
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25^{\circ}C$			1.0	mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=450A, V_{GE}=15V, T_{vj}=25^{\circ}C$		1.85	2.20	V
		$I_C=450A, V_{GE}=15V, T_{vj}=125^{\circ}C$		2.15		
		$I_C=450A, V_{GE}=15V, T_{vj}=150^{\circ}C$		2.25		
Gate Charge	Q_G			3.50		uC
Internal Gate Resistance	R_{Gint}			1.67		Ω
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V,$ $f=1MHz, T_{vj}=25^{\circ}C$		25.0		nF
Reverse Transfer Capacitance	C_{res}			1.10		nF
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA
Turn-on Delay Time	$t_{d(on)}$	$I_C=450A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_{Gon}=1.3\Omega$ $R_{Goff}=1.8\Omega$ $T_{vj}=25^{\circ}C$		228		ns
Rise Time	t_r			96		ns
Turn-off Delay Time	$t_{d(off)}$			361		ns
Fall Time	t_f			154		ns
Energy Dissipation During Turn-on Time	E_{on}			52.1		mJ
Energy Dissipation During Turn-off Time	E_{off}			38.2		mJ
Turn-on Delay Time	$t_{d(on)}$	$I_C=450A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_{Gon}=1.3\Omega$ $R_{Goff}=1.8\Omega$ $T_{vj}=125^{\circ}C$		236		ns
Rise Time	t_r			106		ns
Turn-off Delay Time	$t_{d(off)}$			412		ns
Fall Time	t_f			244		ns
Energy Dissipation During Turn-on Time	E_{on}			72.1		mJ
Energy Dissipation During Turn-off Time	E_{off}			49.1		mJ
Turn-on Delay Time	$t_{d(on)}$	$I_C=450A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_{Gon}=1.3\Omega$ $R_{Goff}=1.8\Omega$ $T_{vj}=150^{\circ}C$		245		ns
Rise Time	t_r			116		ns
Turn-off Delay Time	$t_{d(off)}$			436		ns
Fall Time	t_f			265		ns
Energy Dissipation During Turn-on Time	E_{on}			84.6		mJ
Energy Dissipation During Turn-off Time	E_{off}			57.9		mJ
SC Data	I_{sc}	$t_p \leq 10\mu s, V_{GE}=15V,$ $T_{vj}=150^{\circ}C, V_{CC}=900V,$ $V_{CEM} \leq 1200V$		2250		A



● Diode

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25^{\circ}\text{C}$	1200	V
Continuous DC Forward Current	I_F		450	A
Repetitive Peak Forward Current	I_{FRM}	$t_p=1\text{ms}$	900	A
I^2t -value	I^2t	$V_R=0\text{V}, t_p=10\text{ms}, T_{vj}=125^{\circ}\text{C}$	32000	A^2s
		$V_R=0\text{V}, t_p=10\text{ms}, T_{vj}=150^{\circ}\text{C}$	30000	

Characteristic Values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	V_F	$I_F=450\text{A}, T_{vj}=25^{\circ}\text{C}$		1.90		V
		$I_F=450\text{A}, T_{vj}=125^{\circ}\text{C}$		1.80		
		$I_F=450\text{A}, T_{vj}=150^{\circ}\text{C}$		1.75		
Recovered Charge	Q_{rr}	$I_F=450\text{A}$		26.8		μC
Peak Reverse Recovery Current	I_{rr}	$V_R=600\text{V}$ $-di_F/dt=4600\text{A}/\mu\text{s}$		155		A
Reverse Recovery Energy	E_{rec}	$T_{vj}=25^{\circ}\text{C}$		7.9		mJ
Recovered Charge	Q_{rr}	$I_F=450\text{A}$		75.4		μC
Peak Reverse Recovery Current	I_{rr}	$V_R=600\text{V}$ $-di_F/dt=4600\text{A}/\mu\text{s}$		258		A
Reverse Recovery Energy	E_{rec}	$T_{vj}=125^{\circ}\text{C}$		24.9		mJ
Recovered Charge	Q_{rr}	$I_F=450\text{A}$		82.5		μC
Peak Reverse Recovery Current	I_{rr}	$V_R=600\text{V}$ $-di_F/dt=4600\text{A}/\mu\text{s}$		320		A
Reverse Recovery Energy	E_{rec}	$T_{vj}=150^{\circ}\text{C}$		36.3		mJ

● NTC-Thermistor

Characteristic values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Rated Resistance	R_{25}			5.0		$\text{k}\Omega$
Deviation of R_{100}	$\Delta R/R$	$T_C=100, R_{100}=493.3\Omega$	-5		5	%
Power Dissipation	P_{25}				20.0	mW
B-value	$B_{25/50}$	$R_2=R_{25}\exp[B_{25/50}(1/T_2-1/(298.15\text{K}))]$		3375		K



MG450HF12TLE3

RoHS
COMPLIANT

● Module Characteristics

T_C=25°C unless otherwise specified

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Isolation voltage	V _{isol}	t=1min,f=50Hz	2500			V
Maximum Junction Temperature	T _{jmax}				175	°C
Operating Junction Temperature	T _{vj op}		-40		150	°C
Storage Temperature	T _{stg}		-40		125	°C
Thermal Resistance Junction-to Case	R _{θJC}	per IGBT			0.065	K/W
		per Diode			0.13	
Thermal Resistance Case-to Sink	R _{θCS}	Conductive grease applied		0.009		K/W
Comparative Tracking Index	CTI			>200		
Module Electrodes Torque	M _t	Recommended(M5)	3.0		5.0	N·m
Module-to-Sink Torque	M _s	Recommended(M6)	3.0		5.0	N·m
Weight of Module	G			345		g

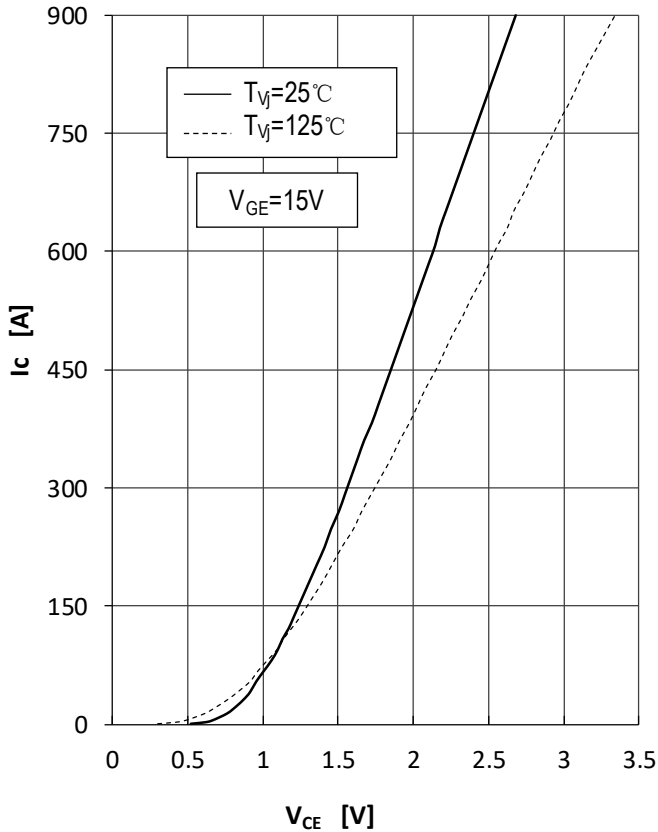


Fig1.IGBT Output Characteristics

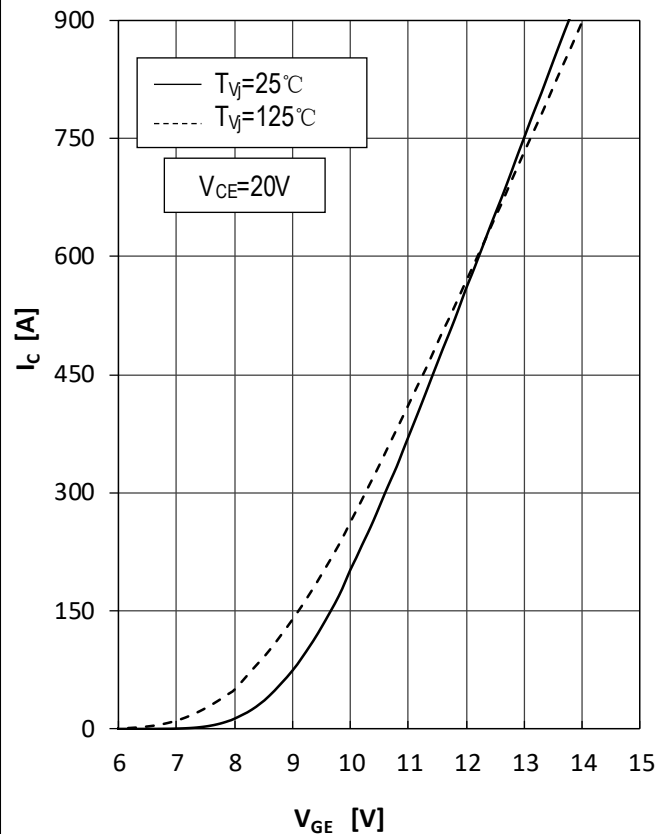


Fig2.IGBT Transfer Characteristics

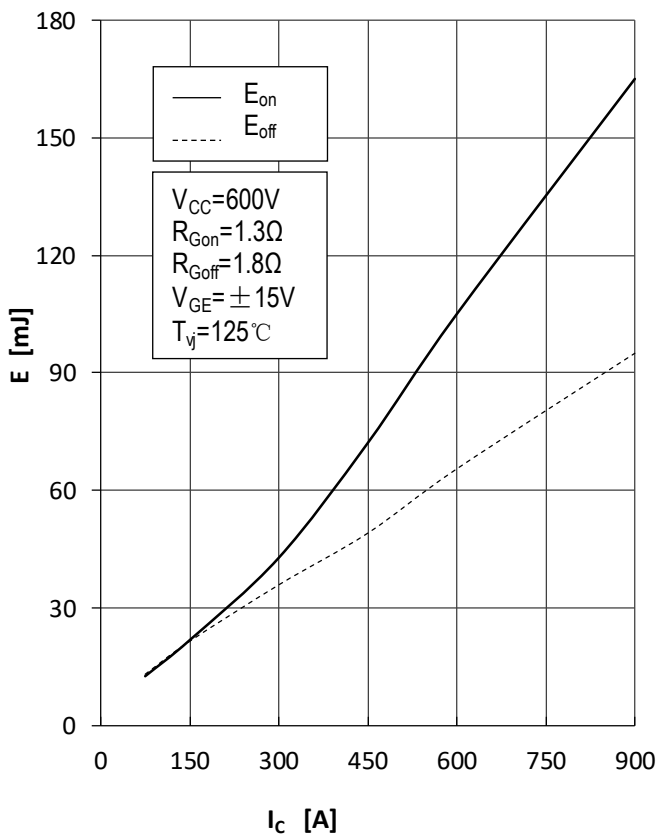


Fig3.IGBT Switching Loss vs. I_c

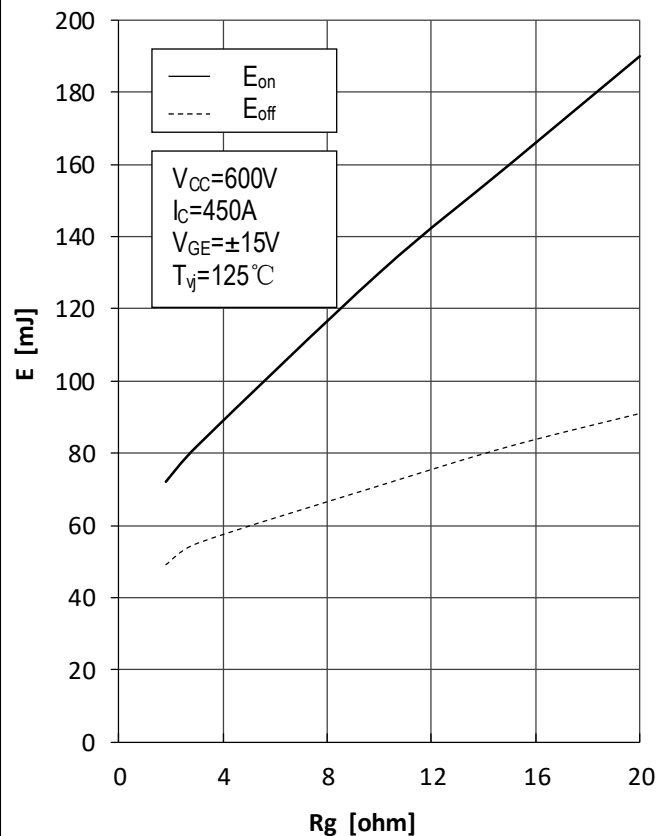
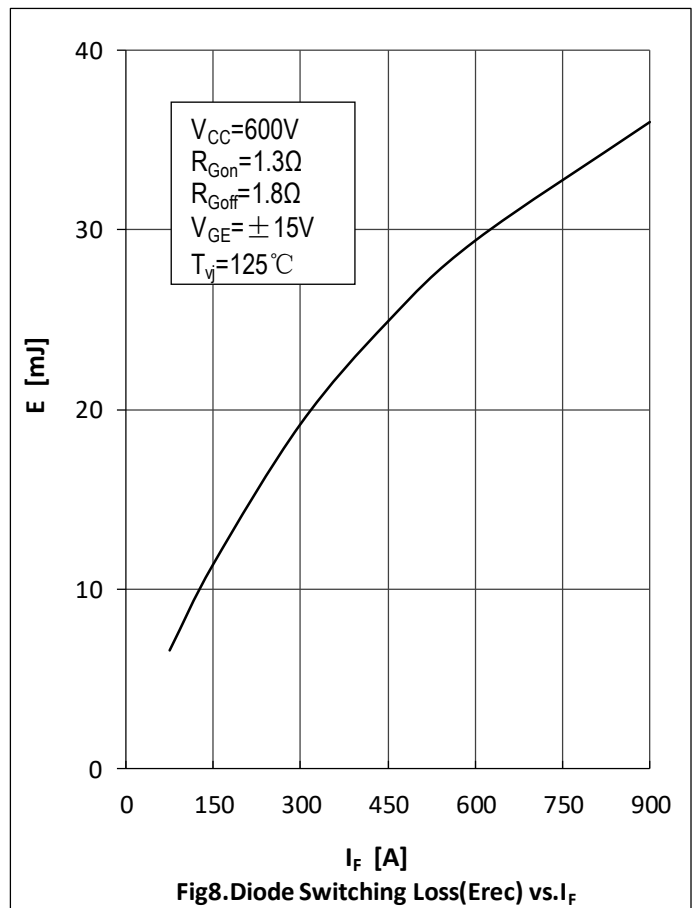
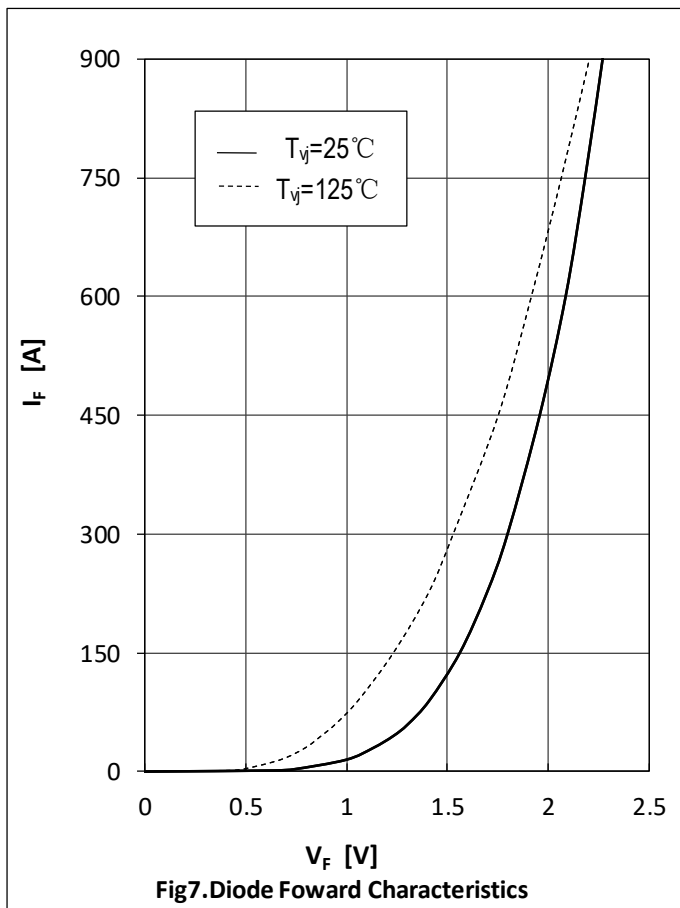
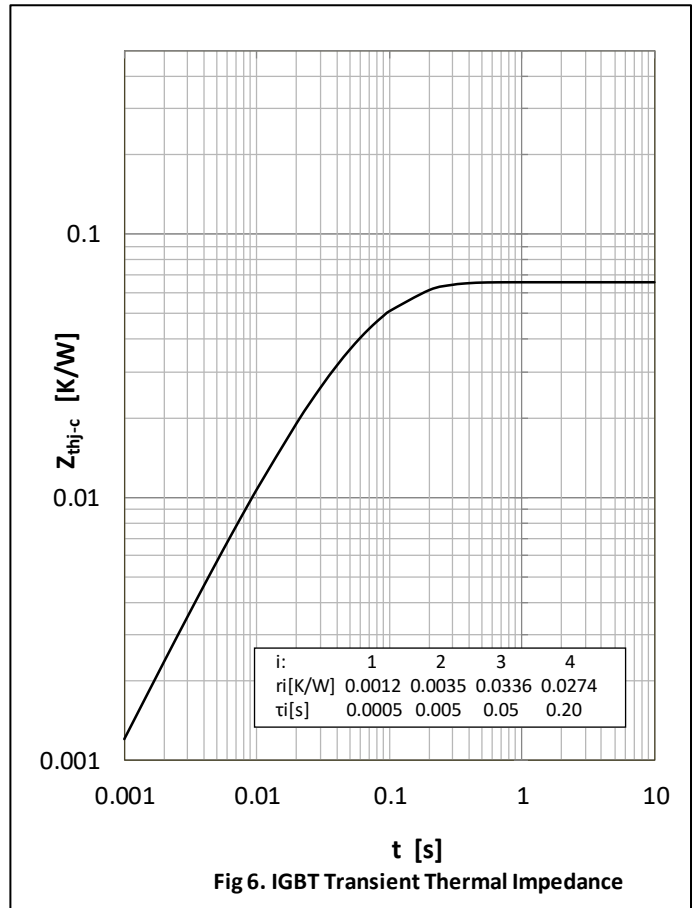
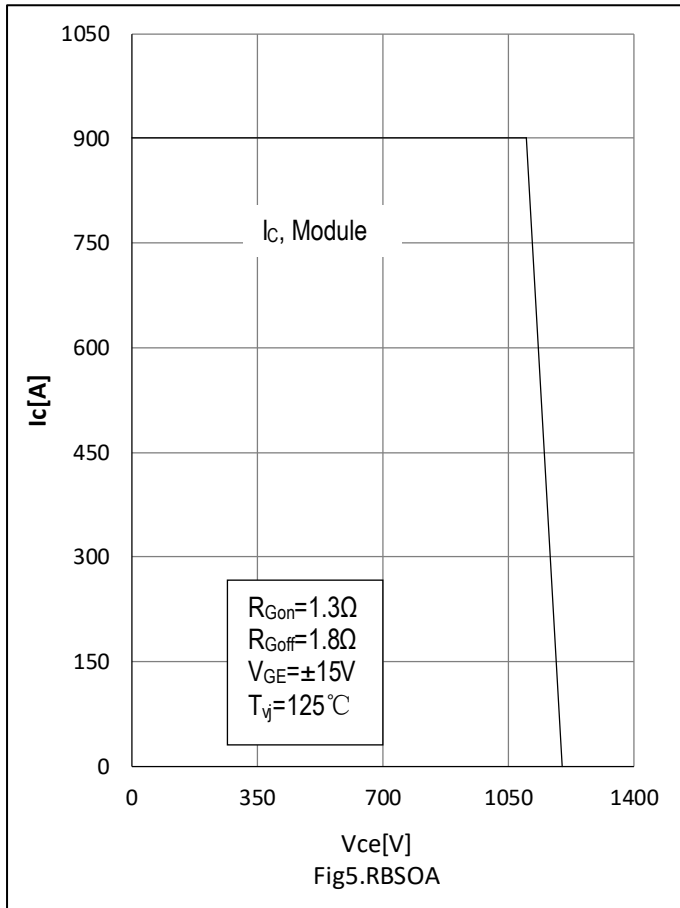
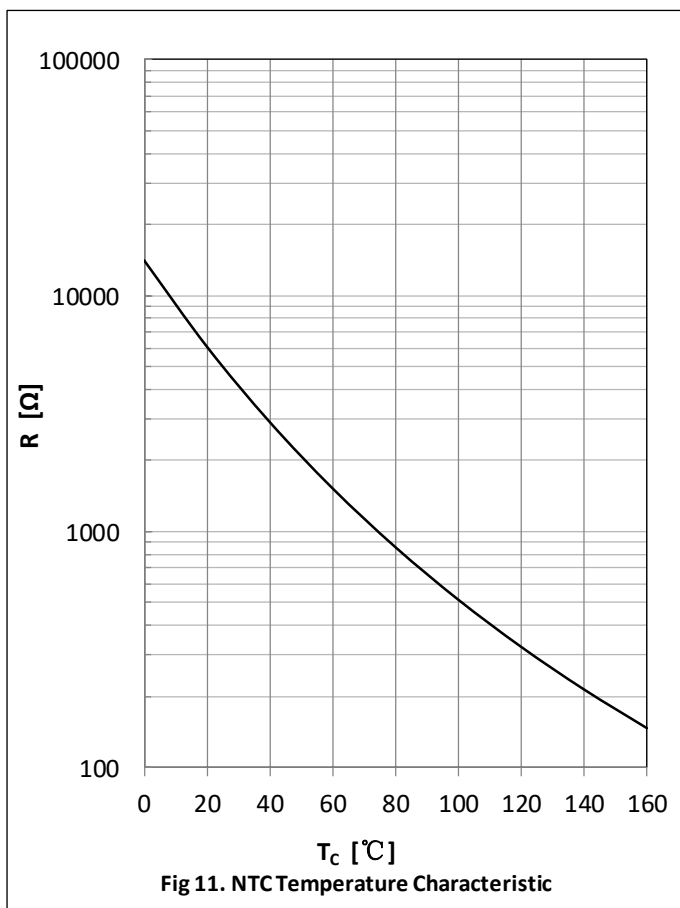
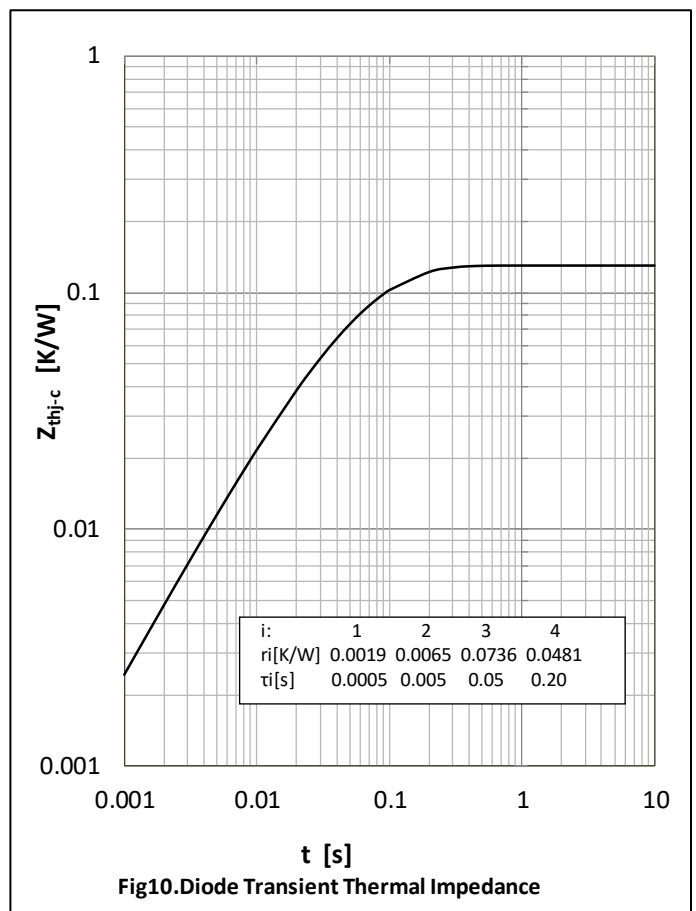
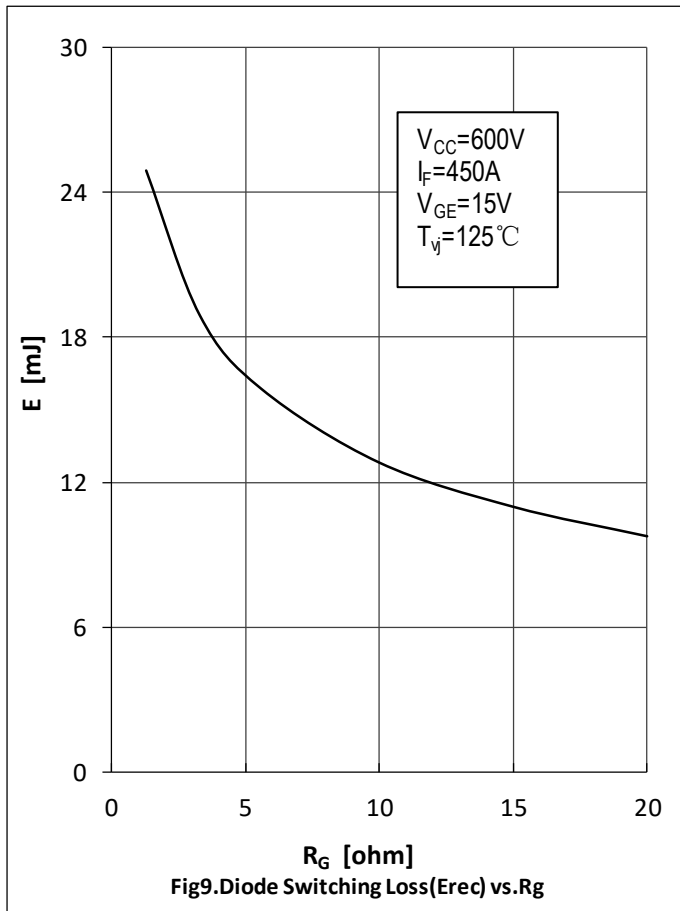
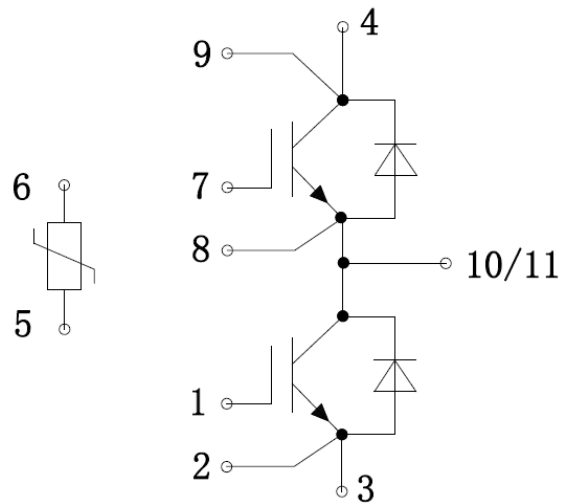


Fig4.IGBT Switching Loss vs. R_g

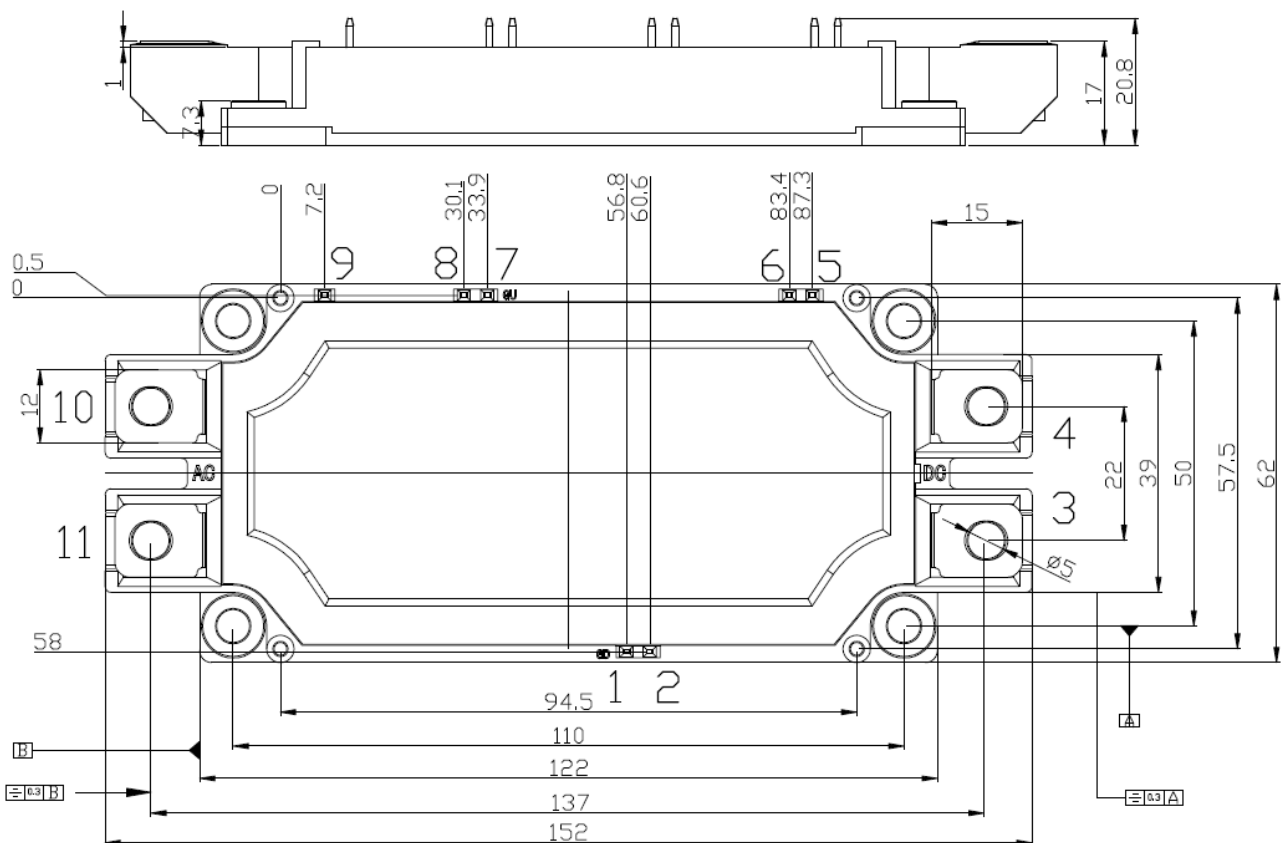




- **Circuit Diagram**



● Package Outline Information





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